

InAsSb photovoltaic detectors



P13243 series

High sensitivity, high-speed response infrared detectors with large photosensitive area (up to 5 µm band)

The P13424 series are photovoltaic type detectors that have high sensitivity in the spectral band up to 5 µm band. These products are environmentally friendly as they do not use lead, mercury, or cadmium which are substances restricted by the RoHS Directive. Therefore, they are replacements for previous products that contain these substances. The easily handled non-cooled type and the TE-cooled type capable of stable high S/N measurement are available.

Features

- High sensitivity
- → High-speed response
- → High shunt resistance
- RoHS compliant (lead, mercury, cadmium free)

Applications

- Gas detection (CH4, CO2, CO, etc.)
- Radiation thermometers
- ➡ Flame detection (CO₂ resonance radiation)

Options (sold separately)

| ■ Heatsink for one-stage TE-cooled type | A3179 |
|--|----------|
| ■ Heatsink for two-stage TE-cooled type | A3179-01 |
| ■ Temperature controller for TE-cooled type | C1103-04 |
| ■ Amplifier for infrared detector | C4159-01 |

Structure

| Type no. | Photosensitive area (mm) | Package | Window material | Cooling | Field of view FOV (degrees) |
|--------------|--------------------------|---------|-----------------|---------------------|-----------------------------------|
| P13243-022MS | | TO-5 | | Non-cooled | 97 |
| P13243-122MS | 2 × 2 | TO-8 | Sapphire | One-stage TE-cooled | 134 |
| P13243-222MS | | 10-8 | | Two-stage TE-cooled | 113 |

- Absolute maximum ratings

| Type no. | TE-cooler allowable current (A) | Thermistor power dissipation (mW) | Reverse voltage VR (V) | Operating temperature Topr* ¹ (°C) | Storage temperature Tstg* ¹ (°C) | Incident light level Pin (W/mm²) |
|--------------|--|--|------------------------------|--|--|---|
| P13243-022MS | - | - | | -40 to +85 | -40 to +85 | |
| P13243-122MS | 1.5 | 0.2 | 1 | -40 to +60 | -40 to +60 | 1 |
| P13243-222MS | 1.0 | 0.2 | | -40 10 +60 | -40 10 +60 | |

^{*1:} No dew condensation

When there is a temperature difference between a product and the surrounding area in high humidity environments, dew condensation may occur on the product surface. Dew condensation on the product may cause deterioration in characteristics and reliability.

Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

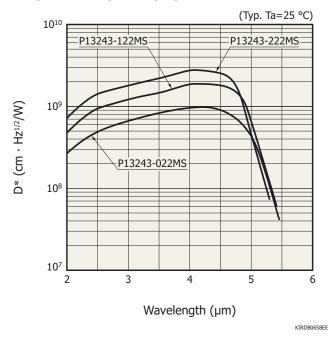
➡ Electrical and optical characteristics (Typ. Ta=25 °C, unless otherwise noted)

| Type no. | Chip temperature Tchip | Peak sensitivity wavelength λp | Cutoff wavelength \(\lambda\)C | Photosensitivity S*2 λ=λp | Shunt resistance Rsh VR=10mV | D (λp, 12 | ctivity)* 200, 1) | pov N | quivalent wer EP λρ | Rise time tr*3 | Terminal capacitance |
|--------------|------------------------------|---|--------------------------------------|---------------------------|---------------------------------------|---------------------------|---------------------------|------------------------|------------------------------|----------------------|----------------------|
| | | | | | | Min. | Тур. | Тур. | Max. | | |
| | (°C) | (µm) | (µm) | (mA/W) | (kΩ) | (cm·Hz ^{1/2} /W) | (cm·Hz ^{1/2} /W) | (W/Hz ^{1/2}) | (W/Hz ^{1/2}) | (ns) | (pF) |
| P13243-022MS | 25 | | 5.3 | 8.0 | 7 | 8.0×10^{8} | 1.0×10^{9} | 2.0×10^{-10} | 2.5×10^{-10} | | |
| P13243-122MS | -10 | 4.1 | 5.2 | 8.6 | 19 | 1.0×10^{9} | 1.9×10^{9} | 1.0×10^{-10} | 2.0×10^{-10} | 100 | 20 |
| P13243-222MS | -30 | | 5.1 | 8.8 | 33 | 1.6×10^{9} | 2.8×10^{9} | 0.7×10^{-10} | 1.3×10^{-10} | | |

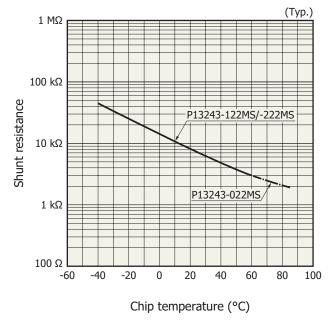
^{*2:} Uniform irradiation on the entire photosensitive area

Note: Uniform irradiation must be applied to the entire photosensitive area during use.

► Spectral response (D*)



Shunt resistance vs. chip temperature

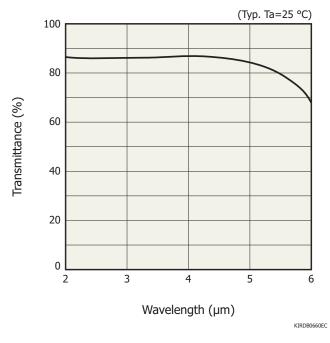


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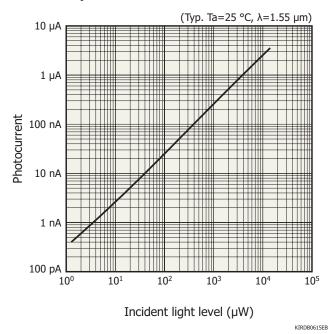
^{*3:} VR=0 V, $RL=50 \Omega$, 10 to 90%, $\lambda=1.55 \mu m$

^{*4:} VR=0 V, f=1 MHz

Spectral transmittance of window materials



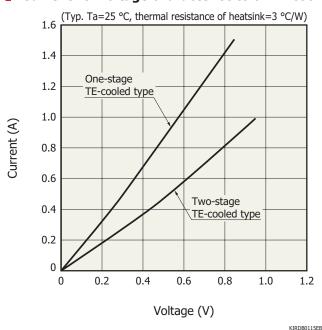
Linearity



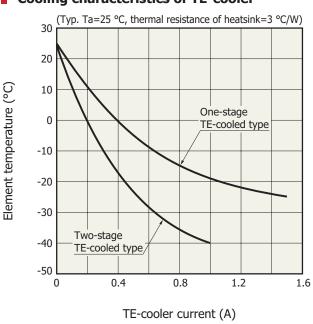
■ TE-cooler specifications (Ta=25 °C, unless otherwise noted)

| Parameter | Condition | Symbol | Min. | Тур. | Max. | Unit | |
|------------------------------|---------------------|----------|------|------|------|------|--|
| TE-cooler allowable current | One-stage TE-cooled | Ic max | - | - | 1.5 | ۸ | |
| 1L-cooler allowable current | Two-stage TE-cooled | IC IIIax | - | - | 1.0 | | |
| TE-cooler allowable voltage | One-stage TE-cooled | Vc max | - | - | 1.0 | \/ | |
| | Two-stage TE-cooled | VCIIIdX | - | - | 1.2 | V | |
| Thermistor resistance | | Rth | 8.1 | 9.0 | 9.9 | kΩ | |
| Thermistor B constant | T1=25 °C, T2=-30 °C | В | - | 3298 | - | K | |
| Thermistor power dissipation | | Pth | - | - | 0.2 | mW | |

Current vs. voltage characteristics of TE-cooler



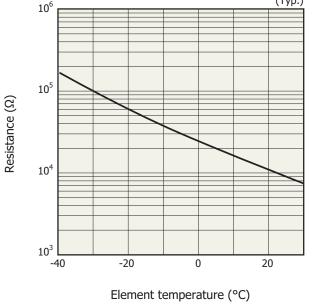
- Cooling characteristics of TE-cooler



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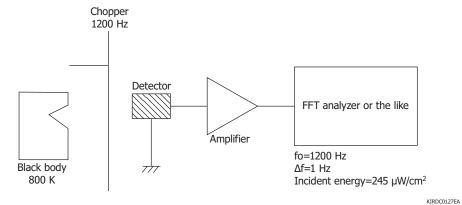
KIRDB0181EA

► Thermistor temperature characteristics



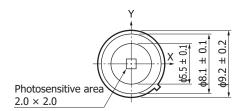
KIRDB0116EA

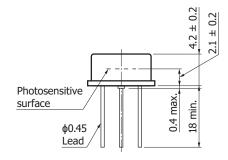
Block diagram for characteristic measurement

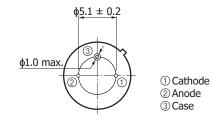


Dimensional outlines (unit: mm)

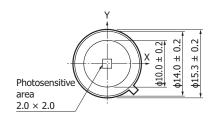
P13243-022MS

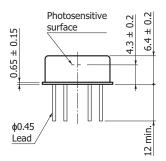


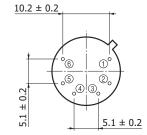




P13243-122MS





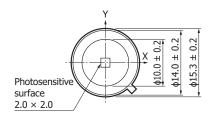


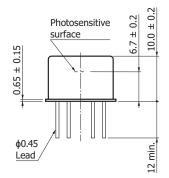
Distance from photosensitive area center to cap center -0.3≤X≤+0.3 -0.3≤Y≤+0.3

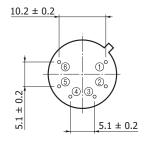
- ① Detector (anode)
- ② Detector (allode)
 ② Detector (cathode)
 ③ TE-cooler (-)
 ④ TE-cooler (+)
 ⑤⑥ Thermistor

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P13243-222MS







Distance from photosensitive area center to cap center -0.3≤X≤+0.3 -0.3≤Y≤+0.3

- ① Detector (anode)
 ② Detector (cathode)
 ③ TE-cooler (-)
 ④ TE-cooler (+)
 ⑤ ⑥ Thermistor

KIRDA0261EE

Recommended soldering conditions

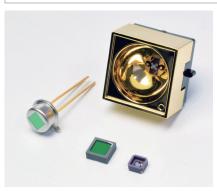
· Solder temperature: 260 °C (10 s or less, once)

Solder the leads at a point at least 1 mm away from the package body.

Note: When you set soldering conditions, check that problems do not occur in the product by testing out the condition in advance.

Related products

Mid infrared LED L15893/L15894/L15895 series



Hamamatsu's unique crystal growth and process technologies enable mid infrared LEDs with peak emission wavelengths of 3.3 μ m, 3.9 μ m, and 4.3 μ m.

| Type no. | Package |
|---|----------------------|
| L15893-0330C/CN, L15894-0390C/CN, L15895-0430C/CN | Ceramic |
| L15893-0330MA, L15894-0390MA, L15895-0430MA | TO-46 |
| L15893-0330ML, L15894-0390ML, L15895-0430ML | TO-46 with reflector |

Related information

www.hamamatsu.com/sp/ssd/doc_en.html

- Precautions
- Disclaimer
- · Safety consideration
- · Compound opto-semiconductors (photosensors, light emitters)
- Technical note
- · Compound semiconductor photosensors

Information described in this material is current as of October 2023.

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